Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN0606-3 (SOT8001) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Very fast switching
- · Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Leadless ultra small and ultra thin SMD plastic package: 0.62 × 0.62 × 0.37 mm

3. Applications

- Relay driver
- High-speed line driver
- · High-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V	
V _{GS}	gate-source voltage			-8	-	8	V	
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-530	mA	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -500 \text{ mA}; T_j = 25 \text{ °C}$		-	1	1.4	Ω	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	Transparent top view DFN0606-3 (SOT8001)	G S S 017aaa259

6. Ordering information

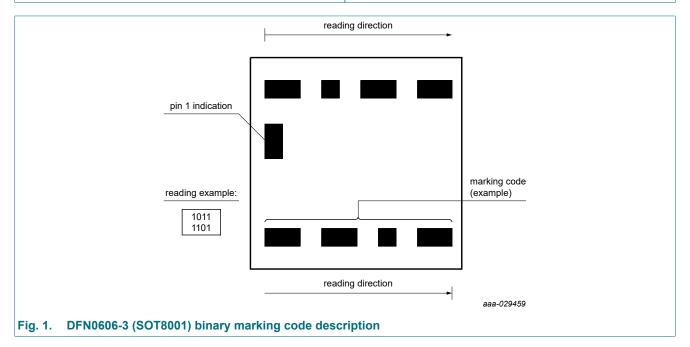
Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMH950UPE		plastic, leadless ultra small package; 3 terminals; body 0.62 x 0.62 x 0.37 mm	SOT8001			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMH950UPE	0001 0100



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V_{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-530	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-360	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-2	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	370	mW
			[1]	-	625	mW
		T _{sp} = 25 °C		-	2.2	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode			'		
Is	source current	T _{amb} = 25 °C	[1]	-	-530	mA

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

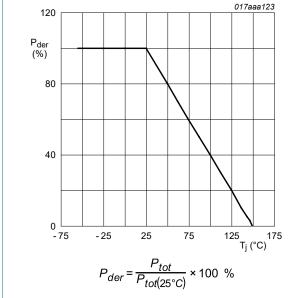


Fig. 2. Normalized total power dissipation as a function of junction temperature

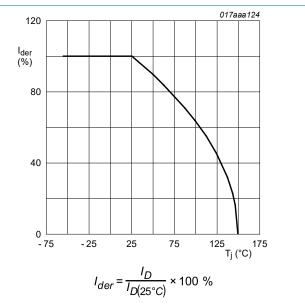


Fig. 3. Normalized continuous drain current as a function of junction temperature

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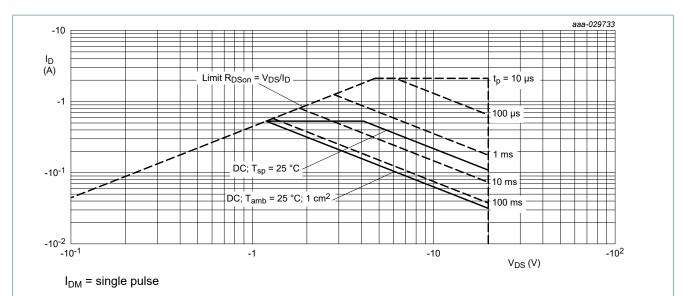


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	300	340	K/W
	junction to ambient		[2]	-	175	200	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	50	58	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².

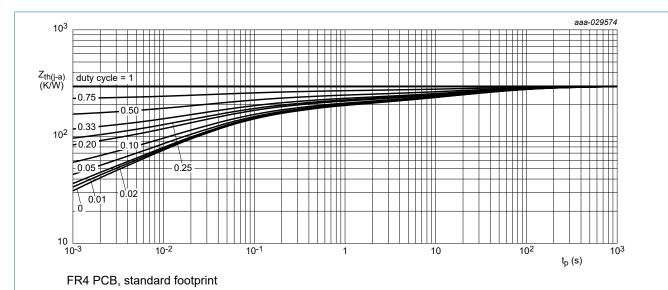


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

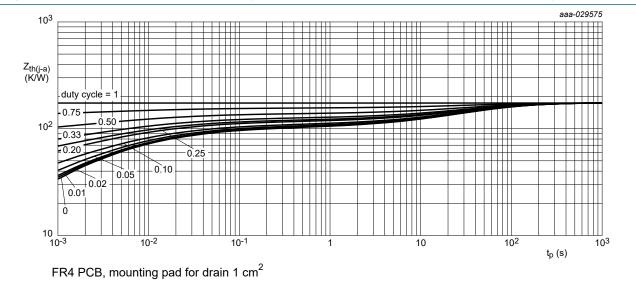


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μΑ
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μΑ
		$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μΑ
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μΑ
		$V_{GS} = 2.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	100	nA
		V _{GS} = -2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	V _{GS} = -4.5 V; I _D = -500 mA; T _i = 25 °C	-	1	1.4	Ω
	resistance	V _{GS} = -4.5 V; I _D = -500 mA; T _i = 150 °C	-	1.6	2.3	Ω
		V _{GS} = -2.5 V; I _D = -200 mA; T _i = 25 °C	-	1.4	2.2	Ω
		V_{GS} = -1.8 V; I_D = -40 mA; T_i = 25 °C	-	1.8	3.3	Ω
		V_{GS} = -1.5 V; I_D = -40 mA; T_i = 25 °C	-	2.1	5.5	Ω
		$V_{GS} = -1.2 \text{ V}; I_D = -10 \text{ mA}; T_i = 25 ^{\circ}\text{C}$	-	2.9	-	Ω
9 _{fs}	forward transconductance	V_{DS} = -10 V; I_{D} = -600 mA; T_{j} = 25 °C	-	700	-	mS
R _G	gate resistance	f = 1 MHz	-	3.7	-	Ω
Dynamic ch	naracteristics		<u> </u>			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I_{D} = -600 mA; V_{GS} = -4 V;	-	0.29	0.5	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.08	-	nC
Q_{GD}	gate-drain charge		-	0.08	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	36	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	6.3	-	pF
C _{rss}	reverse transfer capacitance		-	4.7	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -600 \text{ mA}; V_{GS} = -4 \text{ V};$	-	1	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	2	-	ns
$t_{d(off)}$	turn-off delay time	1	-	4	-	ns
t _f	fall time		-	6	-	ns
Source-drai	in diode					
V _{SD}	source-drain voltage	I _S = -600 mA; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V
	3	, 55				

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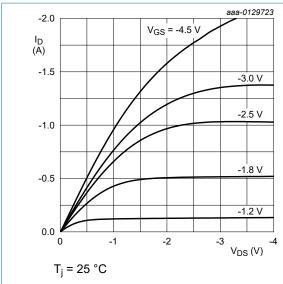


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

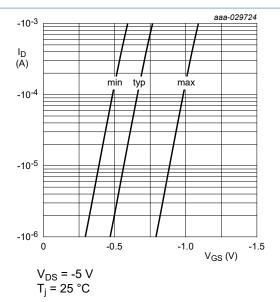


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

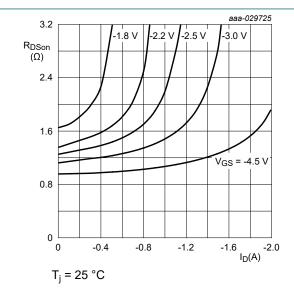


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

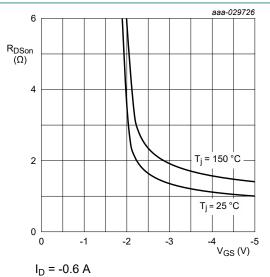


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

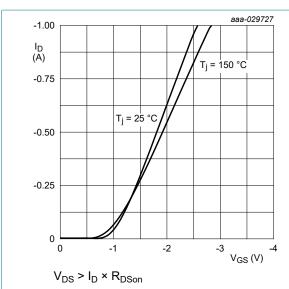


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

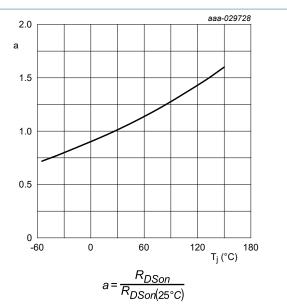


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

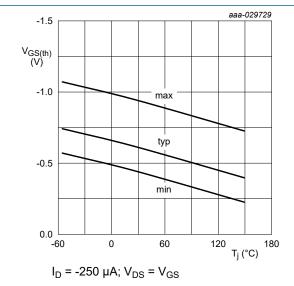


Fig. 13. Gate-source threshold voltage as a function of junction temperature

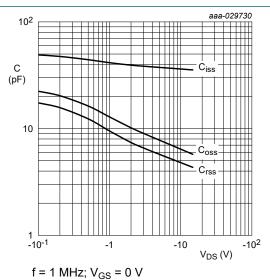


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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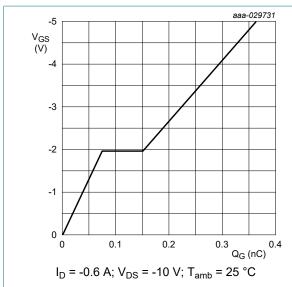


Fig. 15. Gate-source voltage as a function of gate charge; typical values

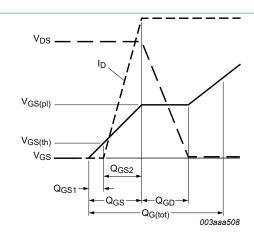


Fig. 16. Gate charge waveform definitions

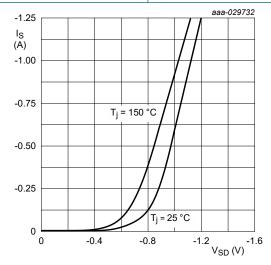
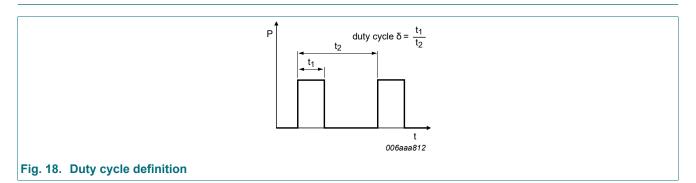


Fig. 17. Source current as a function of source-drain voltage; typical values

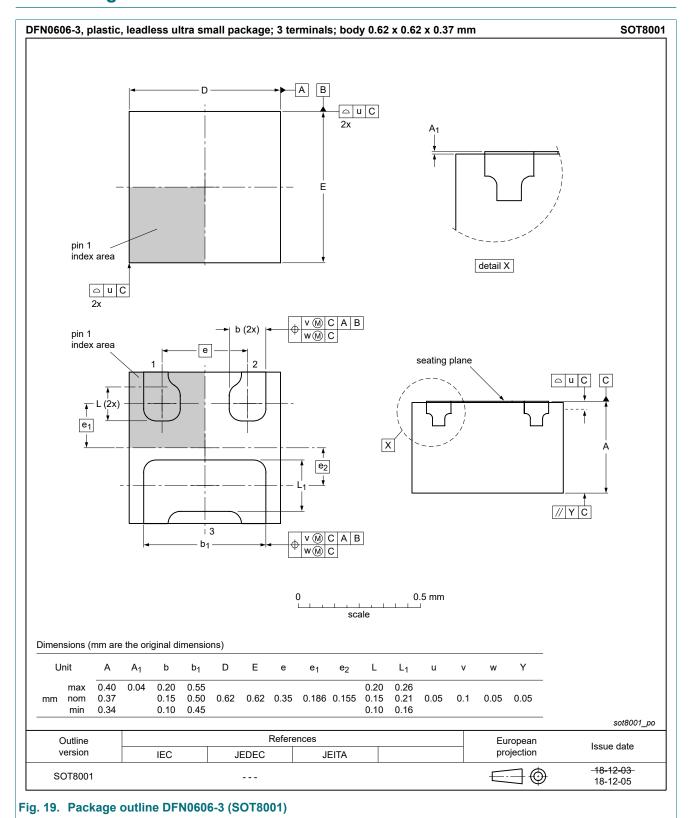
11. Test information

 $V_{GS} = 0 V$



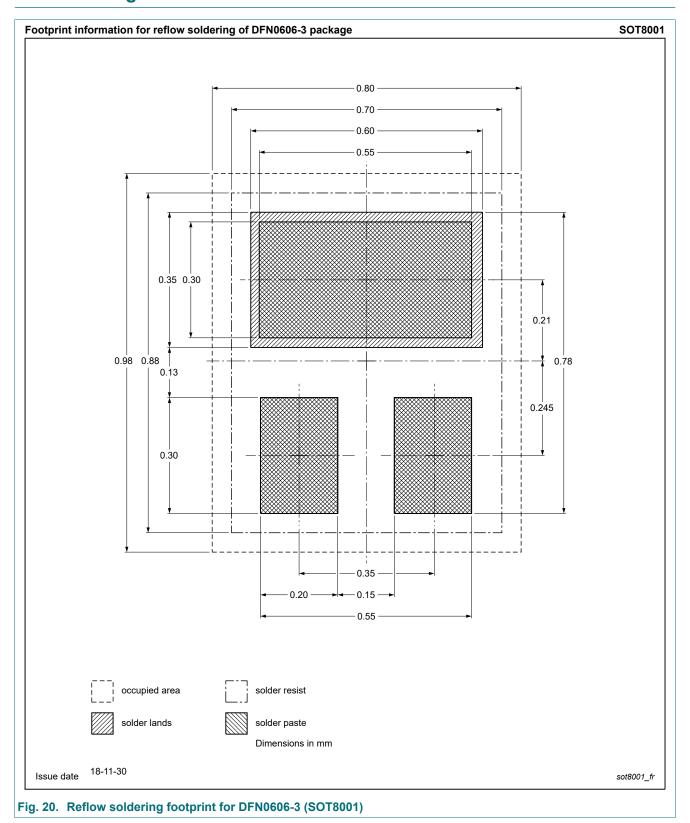
PMH950UPE

12. Package outline



Product data sheet

13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMH950UPE v.1	20190405	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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